

	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	1783	(semiconductor near wafer or wafer) and damascene	USPAT	2003/01/07 18:31
2	BRS	1	(semiconductor near wafer) with damascene with center	USPAT	2003/01/07 18:34
3	BRS	1	(semiconductor near wafer) same damascene with center	USPAT	2003/01/07 18:34
4	BRS	3	(semiconductor near wafer) and damascene with center	USPAT	2003/01/07 18:35
5	BRS	870	(semiconductor near wafer) and damascene	USPAT	2003/01/07 18:37
6	BRS	61	(semiconductor near wafer) and damascene and (decreas\$3 or reduc\$3) with (edge or peripheral)	USPAT	2003/01/07 18:53
7	BRS	809	(semiconductor near wafer) and damascene not L6	USPAT	2003/01/07 19:07
8	BRS	1	"5629113".PN.	USPAT	2003/01/07 18:54
9	BRS	1	"5764832".PN.	USPAT	2003/01/07 18:54
10	BRS	1	"4845544".PN.	USPAT	2003/01/07 18:55
11	BRS	1	"5011794".PN.	USPAT	2003/01/07 18:56
12	BRS	1	"5196910".PN.	USPAT	2003/01/07 18:56
13	BRS	1	"5626680".PN.	USPAT	2003/01/07 18:56
14	BRS	1	"5712708".PN.	USPAT	2003/01/07 18:57
15	BRS	1	"5830277".PN.	USPAT	2003/01/07 18:57
16	BRS	1	"5838908".PN.	USPAT	2003/01/07 18:57
17	BRS	1	"5991508".PN.	USPAT	2003/01/07 18:57
18	BRS	1	"6025266".PN.	USPAT	2003/01/07 18:57
19	BRS	1	"6030509".PN.	USPAT	2003/01/07 18:57
20	BRS	1	"6035101".PN.	USPAT	2003/01/07 18:57
21	BRS	1	"6035101".PN.	USPAT	2003/01/07 18:58
22	BRS	1	"6043460".PN.	USPAT	2003/01/07 18:58
23	BRS	1	"6134174".PN.	USPAT	2003/01/07 18:58
24	BRS	2	6229172.pn. or 5559051.pn.	USPAT	2003/01/07 19:01

	Type	Hits	Search Text	DBs	Time Stamp
25	BRS	13	"6229172" or "5559051"	USPAT	2003/01/07 19:01
26	BRS	45	(semiconductor near wafer) with (edge or peripheral) and damascene	USPAT	2003/01/07 19:31
27	BRS	1	"5505779".PN.	USPAT	2003/01/07 19:16
28	BRS	1	"5953634".PN.	USPAT	2003/01/07 19:16
29	BRS	1	"6133144".PN.	USPAT	2003/01/07 19:17
30	BRS	1	"6149730".PN.	USPAT	2003/01/07 19:17
31	BRS	1	"6093087".PN.	USPAT	2003/01/07 19:25
32	BRS	1	"5944584".PN.	USPAT	2003/01/07 19:25
33	BRS	1	"5882539".PN.	USPAT	2003/01/07 19:25
34	BRS	1	"5866477".PN.	USPAT	2003/01/07 19:25
35	BRS	1	"5855735".PN.	USPAT	2003/01/07 19:26
36	BRS	1	"5727990".PN.	USPAT	2003/01/07 19:26
37	BRS	1	"5725414".PN.	USPAT	2003/01/07 19:26
38	BRS	1	"5658189".PN.	USPAT	2003/01/07 19:26
39	BRS	1	"5547415".PN.	USPAT	2003/01/07 19:26
40	BRS	1	"5317836".PN.	USPAT	2003/01/07 19:27
41	BRS	1	"5295331".PN.	USPAT	2003/01/07 19:27
42	BRS	1	"4718202".PN.	USPAT	2003/01/07 19:27
43	BRS	1	"4344260".PN.	USPAT	2003/01/07 19:27
44	BRS	153	(semiconductor near wafer) and wafer with (edge or peripheral) and damascene	USPAT	2003/01/07 20:04
45	BRS	1	"6091130".PN.	USPAT	2003/01/07 19:46
46	BRS	0	(semiconductor near wafer) and wafer with (edge or peripheral) and damascene	JPO	2003/01/07 20:04
47	BRS	0	wafer with (edge or peripheral) and damascene	JPO	2003/01/07 20:11

	Type	Hits	Search Text	DBs	Time Stamp
48	BRS	23	wafer and damascene	JPO	2003/01/07 21:45
49	BRS	248	257/758 and wafer and damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/01/07 20:09
50	BRS	13	(257/758 or 257/759 or 257/760) and wafer with (edge or peripheral) and damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/01/07 20:30
51	BRS	0	(257/755 or 257/756 or 257/757) and wafer with (edge or peripheral) and damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/01/07 20:31
52	BRS	21	(257/762 or 257/751 or 257/754) and wafer with (edge or peripheral) and damascene	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/01/07 20:31
53	BRS	74	(silicon near oxynitride with dielectric near constant) and (silicon near oxide with dielectric near constant)	USPAT	2003/01/07 21:38
54	BRS	104	(silicon near oxynitride with dielectric near constant) and (silicon near oxide with dielectric near constant)	USPAT	2003/01/07 21:40

	Type	Hits	Search Text	DBs	Time Stamp
55	BRS	79	(silicon near oxynitride with dielectric near constant) same (silicon near oxide with dielectric near constant)	USPAT	2003/01/07 21:40
56	BRS	5	11265866.pn. or 5587344.pn. or 2000124216.pn. or 6376363.pn. or 6379782.pn.	USPAT; JPO	2003/01/07 21:46